

Vishay Semiconductors

Standard Recovery Diodes, (Stud Version), 16 A



PRIMARY CHARACTERISTICS				
I _{F(AV)}	16 A			
Package	DO-4 (DO-203AA)			
Circuit configuration	Single			

FEATURES

- · High surge current capability
- Stud cathode and stud anode version



- Wide current range
- Types up to 1200 V V_{RRM}
- · Designed and qualified for industrial and consumer level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- · Battery charges
- Converters
- Power supplies
- Machine tool controls

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{F(AV)}		16	А	
	T _C	140	°C	
I _{F(RMS)}		25	А	
I _{FSM}	50 Hz	350	^	
	60 Hz	370	A A	
I ² t	50 Hz	612	A ² s	
	60 Hz	560		
V_{RRM}	Range	100 to 1200	V	
TJ		-65 to +175	°C	

ELECTRICAL SPECIFICATIONS SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 175 °C mA		
	10	100	150			
	20	200	275			
	40	400	500			
VS-16F(R)	60	600	725	12		
	80	800	950			
	100	1000	1200			
	120	1200	1400			



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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave		16 140	A °C	
Maximum RMS forward current	I _{F(RMS)}				25	A
	()	t = 10 ms	No voltage	Sinusoidal half wave, initial T _J = T _J maximum	350	А
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		370	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		295	
		t = 8.3 ms	reapplied		310	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage		612	A ² s
		t = 8.3 ms	reapplied		560	
		t = 10 ms	100 % V _{RRM} reapplied		435	
		t = 8.3 ms			395	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied		6120	A ² √s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum		0.77	V	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.90]	
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		7.80	mΩ	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ 5.70		5.70	7 11152	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 50 \text{ A}, T_J = 25 ^{\circ}\text{C}, t_p = 400 \mu \text{s} \text{ rectangular wave}$		1.23	V	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating temperature range	Tu		-65 to +175	°C
Maximum storage temperature range	T _{Stg}		-65 to +200	
Maximum thermal resistance, junction to case	R _{thJC}	R _{thJC} DC operation		K/W
Maximum thermal resistance, case to heat sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.5	IV VV
Allowable mounting torque		Not lubricated threads	1.5 + 0 - 10 % (13)	$N \cdot m$ (lbf \cdot in)
Allowable mounting torque		Lubricated threads	1.2 + 0 - 10 % (10)	$N \cdot m$ (lbf \cdot in)
Approximate weight			7	g
Approximate weight			0.25	oz.
Case style		See dimensions - link at the end of datasheet DO-4 (DO-203AA)		-203AA)

△R _{thJC} CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.31	0.23			
120°	0.38	0.40			
90°	0.49	0.54	$T_J = T_J$ maximum	K/W	
60°	0.72	0.75			
30°	1.20	1.21	1		

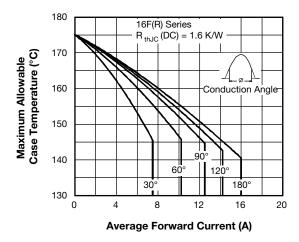
Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC



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180 16F(R) Series R_{thJC} (DC) = 1 170 Maximum Allowable Case Temperature (°C) 160 Conduction Period 150 140 60 ĎС 130 0 5 10 15 20 25 30 **Average Forward Current (A)**

Fig. 1 - Current Ratings Characteristics

Fig. 2 - Current Ratings Characteristics

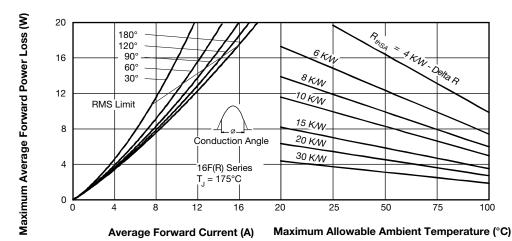


Fig. 3 - Forward Power Loss Characteristics

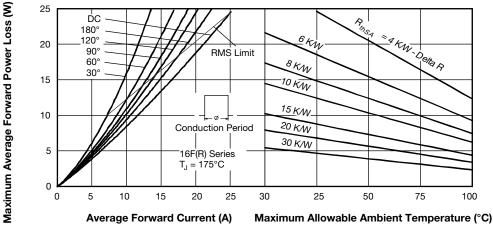


Fig. 4 - Forward Power Loss Characteristics

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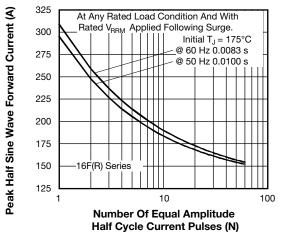


Fig. 5 - Maximum Non-Repetitive Surge Current

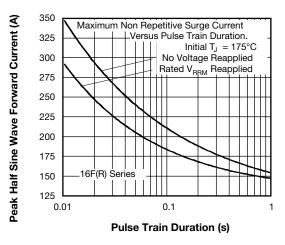


Fig. 6 - Maximum Non-Repetitive Surge Current

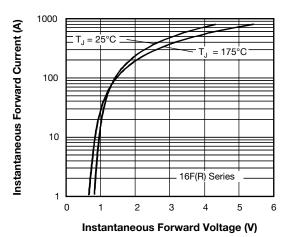


Fig. 7 - Forward Voltage Drop Characteristics

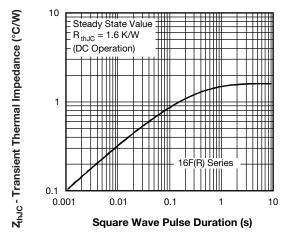
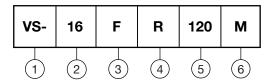


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating: code = I_{F(AV)}
- 3 F = standard device
- None = stud normal polarity (cathode to stud)
 R = stud reverse polarity (anode to stud)
- 5 Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
- 6 None = stud base DO-4 (DO-203AA) 10-32UNF-2A M = stud base DO-4 (DO-203AA) M5 x 0.8

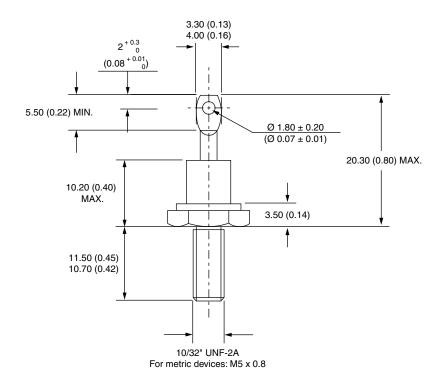
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95311			

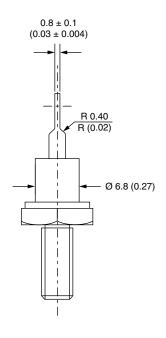


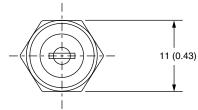
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DO-203AA (DO-4)

DIMENSIONS in millimeters (inches)







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